

GEMOLOGICAL INSTITUTE

ELECTRONIC COPY

LABORATORY GROWN DIAMOND REPORT

PROPORTIONS

CLARITY CHARACTERISTICS

KEY TO SYMBOLS

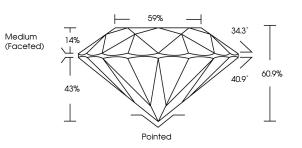
Red symbols indicate internal characteristics.

Green symbols indicate external characteristics.

May 3, 2024	
IGI Report Number	LG633406138
Description	LABORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	8.10 - 8.16 X 4.95 MM
GRADING RESULTS	
Carat Weight	2.01 CARATS
Color Grade	
Clarity Grade	V\$ 2
Cut Grade	IDEAL
ADDITIONAL GRADING I	NFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	1G1 LG633406138

Comments: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process and may include post-growth treatment. Type IIa



LG633406138

Report verification at igi.org



Sample Image Used

COLOR

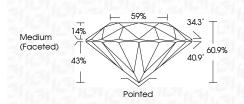
D E F	GHIJ	Faint	Very Light	Light
CLARITY	WS ¹⁻²	VS ¹⁻²	SI ¹⁻²	1 ¹⁻³
Internally Flawless	Very Very Slightly Included	Very Slightly Included	Slightly Included	Included
		Ph GEMOLOG		
		1975		
© I	GI 2020, International G	Gemological Institute		FD - 10 20
	No			17.15



DIAMOND REPORT

May 3, 2024

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IGI Report Number	LG633406138
Description LA	BORATORY GROWN DIAMOND
Shape and Cutting Style	ROUND BRILLIANT
Measurements	8.10 - 8.16 X 4.95 MM
GRADING RESULTS	
Carat Weight	2.01 CARATS
Color Grade	E
Clarity Grade	VS 2
Cut Grade	IDEAL



ADDITIONAL GRADING INFORMATION

Polish	EXCELLENT
Symmetry	EXCELLENT
Fluorescence	NONE
Inscription(s)	1671 LG633406138
Comments: This Laboratory of created by Chemical Vapo process and may include po Type IIa	or Deposition (CVD) growth

201 CARATS		VS2	IDEAL	80.9%	869	Medium (Faceted)	Pointed	EXCELLENT	EXCELLENT	NONE	1690 LG633406138	Comments: Na Licholoxy Gown Domord was eached by Chemical Vopor Deposition covidy growth process and may include programment. type IIo	
Carat Weight	Color Grade	Clarity Grade	Cut Grade	Depth	Table	Girdle	Culet	Polish	Symmetry	Fluorescence	Inscription(s)	Comments: This Laboratory Grown created by Chemical V creating growth process: (CVD) growth treatment Type IIa	

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